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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
	A-5-12
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	40MHz
Connectivity	I ² C, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, HLVD, POR, PWM, WDT
Number of I/O	36
Program Memory Size	8KB (4K x 16)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	4.2V ~ 5.5V
Data Converters	A/D 13x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	44-TQFP
Supplier Device Package	44-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic18f4321-i-pt

For PIC18F2685/4685 devices, the code memory space extends from 0000h to 017FFFh (96 Kbytes) in five 16-Kbyte blocks. For PIC18F2682/4682 devices, the code memory space extends from 0000h to 0013FFFh (80 Kbytes) in four 16-Kbyte blocks. Addresses, 0000h through 0FFFh, however, define a "Boot Block" region that is treated separately from Block 0. All of these blocks define code protection boundaries within the code memory space.

The size of the Boot Block in PIC18F2685/4685 and PIC18F2682/4682 devices can be configured as 1, 2 or 4K words (see Figure 2-7). This is done through the BBSIZ<2:1> bits in the Configuration register, CONFIG4L. It is important to note that increasing the size of the Boot Block decreases the size of Block 0.

TABLE 2-3: IMPLEMENTATION OF CODE MEMORY

Device	Code Memory Size (Bytes)
PIC18F2682	000000h 013EEEh (90K)
PIC18F4682	000000h-013FFFh (80K)
PIC18F2685	000000h 017EEEh (06K)
PIC18F4685	000000h-017FFFh (96K)

FIGURE 2-7: MEMORY MAP AND THE CODE MEMORY SPACE FOR PIC18F2685/4685 AND PIC18F2682/4682 DEVICES

000000h		Ì			MEMORY S	IZE/DEVICE			Addres
01FFFFh Code Memory			96 Kbytes (PIC18F2685/4685)			80 Kbytes (PIC18F2682/4682)			- Kang
					BBSIZ1:	:BBSIZ2			
			11/10	01	0.0	11/10	01	00	
				Boot	Boot Block*		Boot	Boot Block*	000000 0007FF
	Unimplemented Read as '0'		Boot Block*	Block*		Boot Block*	Block*		000800 000FFF
									001000
				Block 0	Block 0		Block 0	Block 0	001FFFh 002000h
			Block 0			Block 0			
200000h	200000h				Block 1			003FFF 004000	
			Block 1					007FFF	
				Block 2					
		Configuration and ID Space	51001(2			Block 2			00BFFI
	Configuration		Block 3			Block 3			00C000
			Block 3			Blook 6			00FFFF 010000
				Block 4			Block 4		
									013FFF 014000
			Block 5			Unimplemented		0.4====	
				Inimplemented	d		Reads all '0's		017FFF
BFFFFFh				Reads all '0's					01FFFF

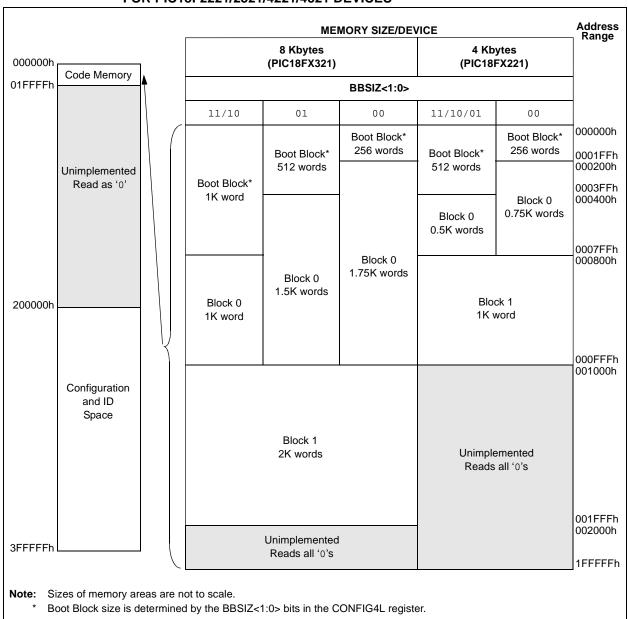
For PIC18FX5X0/X5X3 devices, the code memory space extends from 000000h to 007FFFh (32 Kbytes) in four 8-Kbyte blocks. For PIC18FX4X5/X4X8 devices, the code memory space extends from 000000h to 005FFFh (24 Kbytes) in three 8-Kbyte blocks. Addresses, 000000h through 0007FFh, however, define a "Boot Block" region that is treated separately from Block 0. All of these blocks define code protection boundaries within the code memory space.

The size of the Boot Block in PIC18F2221/2321/4221/4321 devices can be configured as 256, 512 or 1024 words (see Figure 2-11). This is done through the BBSIZ<1:0> bits in the Configuration register, CONFIG4L (see Figure 2-11). It is important to note that increasing the size of the Boot Block decreases the size of Block 0.

TABLE 2-7: IMPLEMENTATION OF CODE MEMORY

Device	Code Memory Size (Bytes)
PIC18F2221	000000h-000FFFh (4K)
PIC18F4221	00000011-000FFF11 (4K)
PIC18F2321	000000h 001EEEh (9K)
PIC18F4321	000000h-001FFFh (8K)

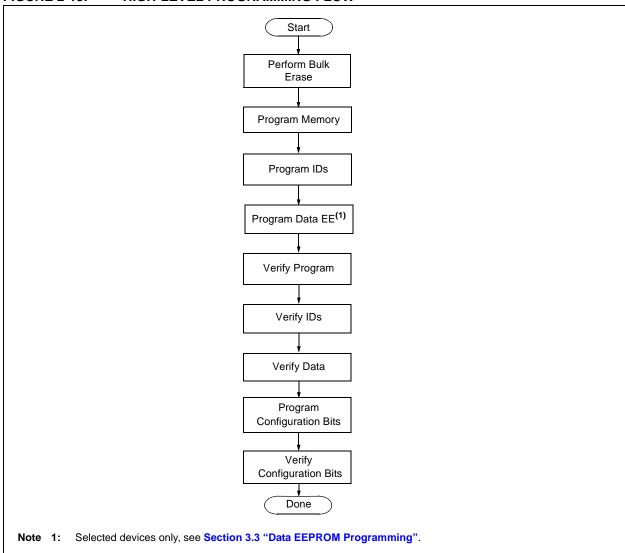
FIGURE 2-11: MEMORY MAP AND THE CODE MEMORY SPACE FOR PIC18F2221/2321/4221/4321 DEVICES



2.4 High-Level Overview of the Programming Process

Figure 2-13 shows the high-level overview of the programming process. First, a Bulk Erase is performed. Next, the code memory, ID locations and data EEPROM are programmed (selected devices only, see **Section 3.3 "Data EEPROM Programming"**). These memories are then verified to ensure that programming was successful. If no errors are detected, the Configuration bits are then programmed and verified.

FIGURE 2-13: HIGH-LEVEL PROGRAMMING FLOW



2.6 Entering and Exiting Low-Voltage ICSP Program/Verify Mode

When the LVP Configuration bit is '1' (see Section 5.3 "Single-Supply ICSP Programming"), the Low-Voltage ICSP mode is enabled. As shown in Figure 2-16, Low-Voltage ICSP Program/Verify mode is entered by holding PGC and PGD low, placing a logic high on PGM and then raising $\overline{\text{MCLR}/\text{VPP/RE3}}$ to VIH. In this mode, the RB5/PGM pin is dedicated to the programming function and ceases to be a general purpose I/O pin. Figure 2-17 shows the exit sequence.

The sequence that enters the device into the Program/Verify mode places all unused I/Os in the high-impedance state.

FIGURE 2-16: ENTERING LOW-VOLTAGE PROGRAM/VERIFY MODE

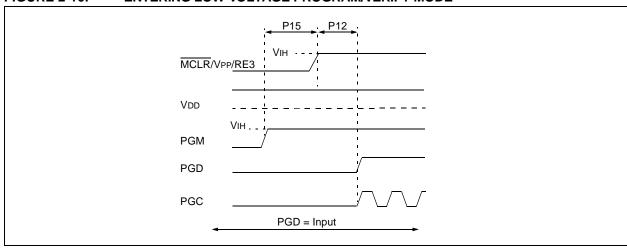


FIGURE 2-17: EXITING LOW-VOLTAGE PROGRAM/VERIFY MODE

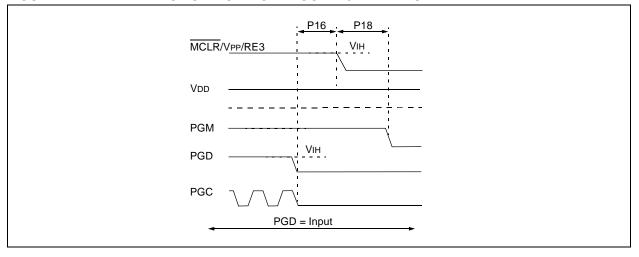
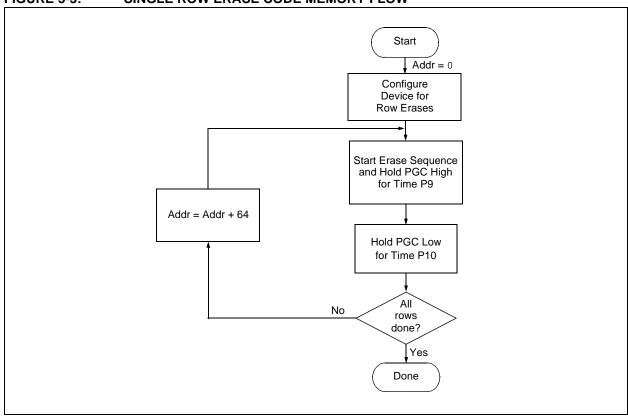


TABLE 3-3: ERASE CODE MEMORY CODE SEQUENCE

Step 1: Direct access to code memory and enable writes. 0000 8E A6 BSF EECON1, EEPGD 0000 9C A6 BCF EECON1, CFGS 0000 84 A6 BSF EECON1, WREN Step 2: Point to first row in code memory. 0000 6A F8 CLRF TBLPTRU 0000 6A F7 CLRF TBLPTRH 0000 6A F6 CLRF TBLPTRL Step 3: Enable erase and erase single row. 0000 88 A6 BSF EECON1, FREE 0000 82 A6 BSF EECON1, WR 0000 00 00 NOP - hold PGC high for time P9 and low for time P10.	4-Bit Command	Data Payload	Core Instruction
0000 9C A6 BCF EECON1, CFGS 0000 84 A6 BSF EECON1, WREN Step 2: Point to first row in code memory. 0000 6A F8 CLRF TBLPTRU 0000 6A F7 CLRF TBLPTRH 0000 6A F6 CLRF TBLPTRL Step 3: Enable erase and erase single row. 0000 88 A6 BSF EECON1, FREE 0000 82 A6 BSF EECON1, WR	Step 1: Direct ac	cess to code memory an	d enable writes.
0000 6A F8 CLRF TBLPTRU 0000 6A F7 CLRF TBLPTRH 0000 6A F6 CLRF TBLPTRL Step 3: Enable erase and erase single row. 0000 88 A6 BSF EECON1, FREE 0000 82 A6 BSF EECON1, WR	0000	9C A6	BCF EECON1, CFGS
0000 6A F7 CLRF TBLPTRH 0000 6A F6 CLRF TBLPTRL Step 3: Enable erase and erase single row. 0000 88 A6 BSF EECON1, FREE 0000 82 A6 BSF EECON1, WR	Step 2: Point to f	irst row in code memory.	
0000 88 A6 BSF EECON1, FREE 0000 82 A6 BSF EECON1, WR	0000	6A F7	CLRF TBLPTRH
0000 82 A6 BSF EECON1, WR	Step 3: Enable e	rase and erase single ro	w.
	0000	82 A6	BSF EECON1, WR

FIGURE 3-3: SINGLE ROW ERASE CODE MEMORY FLOW



3.2 Code Memory Programming

Programming code memory is accomplished by first loading data into the write buffer and then initiating a programming sequence. The write and erase buffer sizes, shown in Table 3-4, can be mapped to any location of the same size, beginning at 000000h. The actual memory write sequence takes the contents of this buffer and programs the proper amount of code memory that contains the Table Pointer.

The programming duration is externally timed and is controlled by PGC. After a Start Programming command is issued (4-bit command, '1111'), a NOP is issued, where the 4th PGC is held high for the duration of the programming time, P9.

After PGC is brought low, the programming sequence is terminated. PGC must be held low for the time specified by Parameter P10 to allow high-voltage discharge of the memory array.

The code sequence to program a PIC18F2XXX/4XXX Family device is shown in Table 3-5. The flowchart, shown in Figure 3-4, depicts the logic necessary to completely write a PIC18F2XXX/4XXX Family device. The timing diagram that details the Start Programming command and Parameters P9 and P10 is shown in Figure 3-5.

Note: The TBLPTR register must point to the same region when initiating the programming sequence as it did when the write buffers were loaded.

TABLE 3-4: WRITE AND ERASE BUFFER SIZES

Devices (Arranged by Family)	Write Buffer Size (Bytes)	Erase Buffer Size (Bytes)	
PIC18F2221, PIC18F2321, PIC18F4221, PIC18F4321	8	64	
PIC18F2450, PIC18F4450	16	64	
PIC18F2410, PIC18F2510, PIC18F4410, PIC18F4510			
PIC18F2420, PIC18F2520, PIC18F4420, PIC18F4520			
PIC18F2423, PIC18F2523, PIC18F4423, PIC18F4523	32	64	
PIC18F2480, PIC18F2580, PIC18F4480, PIC18F4580			
PIC18F2455, PIC18F2550, PIC18F4455, PIC18F4550			
PIC18F2458, PIC18F2553, PIC18F4458, PIC18F4553			
PIC18F2515, PIC18F2610, PIC18F4515, PIC18F4610			
PIC18F2525, PIC18F2620, PIC18F4525, PIC18F4620	64	64	
PIC18F2585, PIC18F2680, PIC18F4585, PIC18F4680	04		
PIC18F2682, PIC18F2685, PIC18F4682, PIC18F4685			

TABLE 3-5: WRITE CODE MEMORY CODE SEQUENCE

4-Bit Command	Data Payload	Core Instruction			
Step 1: Direct access to code memory and enable writes.					
0000	8E A6 9C A6	BSF EECON1, EEPGD BCF EECON1, CFGS			
Step 2: Load write	e buffer.				
0000 0000 0000 0000 0000	0E <addr[21:16]> 6E F8 0E <addr[15:8]> 6E F7 0E <addr[7:0]> 6E F6</addr[7:0]></addr[15:8]></addr[21:16]>	MOVLW <addr[21:16]> MOVWF TBLPTRU MOVLW <addr[15:8]> MOVWF TBLPTRH MOVLW <addr[7:0]> MOVWF TBLPTRL</addr[7:0]></addr[15:8]></addr[21:16]>			
Step 3: Repeat for	r all but the last two byte	es.			
1101	<msb><lsb></lsb></msb>	Write 2 bytes and post-increment address by 2.			
Step 4: Load write buffer for last two bytes.					
1111 0000	<msb><lsb></lsb></msb>	Write 2 bytes and start programming. NOP - hold PGC high for time P9 and low for time P10.			
To continue writing	To continue writing data, repeat Steps 2 through 4, where the Address Pointer is incremented by 2 at each iteration of the loop.				

FIGURE 3-4: PROGRAM CODE MEMORY FLOW

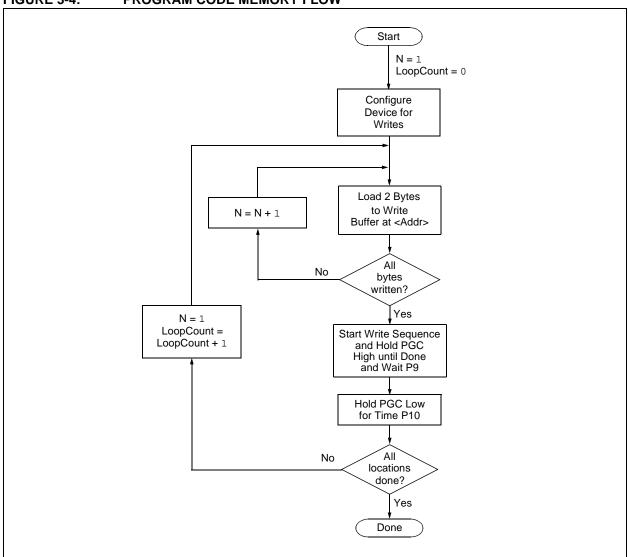
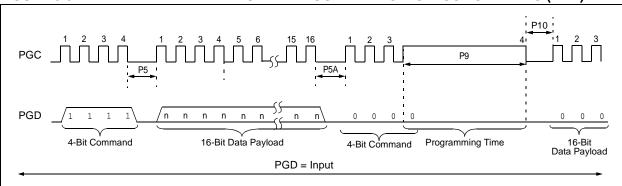


FIGURE 3-5: TABLE WRITE AND START PROGRAMMING INSTRUCTION TIMING (1111)



3.2.1 MODIFYING CODE MEMORY

The previous programming example assumed that the device had been Bulk Erased prior to programming (see Section 3.1.1 "High-Voltage ICSP Bulk Erase"). It may be the case, however, that the user wishes to modify only a section of an already programmed device.

The appropriate number of bytes required for the erase buffer must be read out of code memory (as described in **Section 4.2 "Verify Code Memory and ID Locations"**) and buffered. Modifications can be made on this buffer. Then, the block of code memory that was read out must be erased and rewritten with the modified data.

The WREN bit must be set if the WR bit in EECON1 is used to initiate a write sequence.

TABLE 3-6: MODIFYING CODE MEMORY

TABLE 3-6:	MODIFYING CODE MEMORY					
4-Bit Command	Data Payload	Core Instruction				
Step 1: Direct acc	ess to code memory.					
Step 2: Read and	modify code memory (see S	Section 4.1 "Read Code Memory, ID Locations and Configuration Bits").				
0000	8E A6 9C A6	BSF EECON1, EEPGD BCF EECON1, CFGS				
Step 3: Set the Ta	ble Pointer for the block to b	e erased.				
0000 0000 0000 0000 0000	0E <addr[21:16]> 6E F8 0E <addr[8:15]> 6E F7 0E <addr[7:0]> 6E F6</addr[7:0]></addr[8:15]></addr[21:16]>	MOVLW <addr[21:16]> MOVWF TBLPTRU MOVLW <addr[8:15]> MOVWF TBLPTRH MOVLW <addr[7:0]> MOVWF TBLPTRL</addr[7:0]></addr[8:15]></addr[21:16]>				
Step 4: Enable me	emory writes and set up an e	erase.				
0000	84 A6 88 A6	BSF EECON1, WREN BSF EECON1, FREE				
Step 5: Initiate era	ase.					
0000	82 A6 00 00	BSF EECON1, WR NOP - hold PGC high for time P9 and low for time P10.				
Step 6: Load write	buffer. The correct bytes wi	Il be selected based on the Table Pointer.				
0000 0000 0000 0000 0000 0000 1101	0E <addr[21:16]> 6E F8 0E <addr[8:15]> 6E F7 0E <addr[7:0]> 6E F6 <msb><lsb></lsb></msb></addr[7:0]></addr[8:15]></addr[21:16]>	MOVLW <addr[21:16]> MOVWF TBLPTRU MOVLW <addr[8:15]> MOVWF TBLPTRH MOVLW <addr[7:0]> MOVWF TBLPTRL Write 2 bytes and post-increment address by 2.</addr[7:0]></addr[8:15]></addr[21:16]>				
	•	Repeat as many times as necessary to fill the write buffer				
1111 0000	- <msb><lsb> 00 00</lsb></msb>	Write 2 bytes and start programming. NOP - hold PGC high for time P9 and low for time P10.				
	, , , ,	bugh 6, where the Address Pointer is incremented by the appropriate number of bytes the write cycle must be repeated enough times to completely rewrite the contents of				
Step 7: Disable wi	rites.					
0000	94 A6	BCF EECON1, WREN				

4.0 READING THE DEVICE

4.1 Read Code Memory, ID Locations and Configuration Bits

Code memory is accessed, one byte at a time, via the 4-bit command, '1001' (Table Read, post-increment). The contents of memory pointed to by the Table Pointer (TBLPTRU:TBLPTRH:TBLPTRL) are serially output on PGD.

The 4-bit command is shifted in, LSb first. The read is executed during the next eight clocks, then shifted out on PGD during the last eight clocks, LSb to MSb. A delay of P6 must be introduced after the falling edge of the 8th PGC of the operand to allow PGD to transition from an input to an output. During this time, PGC must be held low (see Figure 4-1). This operation also increments the Table Pointer by one, pointing to the next byte in code memory for the next read.

This technique will work to read any memory in the 000000h to 3FFFFFh address space, so it also applies to the reading of the ID and Configuration registers.

TABLE 4-1: READ CODE MEMORY SEQUENCE

4-Bit Command	Data Payload	Core Instruction
Step 1: Set Table	Pointer.	
0000 0000 0000 0000 0000	0E <addr[21:16]> 6E F8 0E <addr[15:8]> 6E F7 0E <addr[7:0]> 6E F6</addr[7:0]></addr[15:8]></addr[21:16]>	MOVLW Addr[21:16] MOVWF TBLPTRU MOVLW <addr[15:8]> MOVWF TBLPTRH MOVLW <addr[7:0]> MOVWF TBLPTRL</addr[7:0]></addr[15:8]>
Step 2: Read mer	nory and then shift out on P	GD, LSb to MSb.
1001	00 00	TBLRD *+



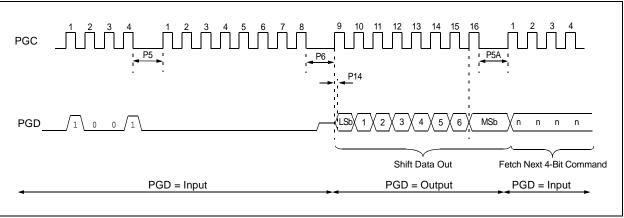
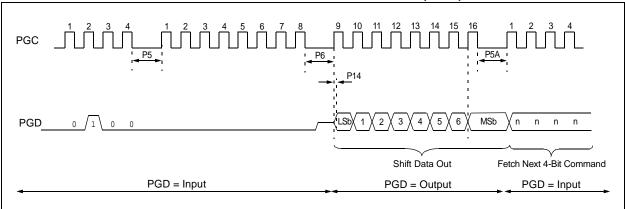


FIGURE 4-4: SHIFT OUT DATA HOLDING REGISTER TIMING (0010)



4.5 Verify Data EEPROM

A data EEPROM address may be read via a sequence of core instructions (4-bit command, '0000') and then output on PGD via the 4-bit command, '0010' (TABLAT register). The result may then be immediately compared to the appropriate data in the programmer's memory for verification. Refer to **Section 4.4 "Read Data EEPROM Memory"** for implementation details of reading data EEPROM.

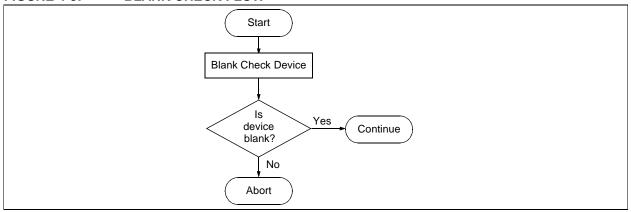
4.6 Blank Check

The term Blank Check means to verify that the device has no programmed memory cells. All memories must be verified: code memory, data EEPROM, ID locations and Configuration bits. The Device ID registers (3FFFFEh:3FFFFh) should be ignored.

A "blank" or "erased" memory cell will read as '1'. Therefore, Blank Checking a device merely means to verify that all bytes read as FFh, except the Configuration bits. Unused (reserved) Configuration bits will read '0' (programmed). Refer to Figure 4-5 for blank configuration expect data for the various PIC18F2XXX/4XXX Family devices.

Given that Blank Checking is merely code and data EEPROM verification with FFh expect data, refer to Section 4.4 "Read Data EEPROM Memory" and Section 4.2 "Verify Code Memory and ID Locations" for implementation details.

FIGURE 4-5: BLANK CHECK FLOW



5.0 CONFIGURATION WORD

The PIC18F2XXX/4XXX Family devices have several Configuration Words. These bits can be set or cleared to select various device configurations. All other memory areas should be programmed and verified prior to setting the Configuration Words. These bits may be read out normally, even after read or code protection. See Table 5-1 for a list of Configuration bits and Device IDs, and Table 5-3 for the Configuration bit descriptions.

5.1 ID Locations

A user may store identification information (ID) in eight ID locations, mapped in 200000h:200007h. It is recommended that the Most Significant nibble of each ID be Fh. In doing so, if the user code inadvertently tries to execute from the ID space, the ID data will execute as a NOP.

5.2 Device ID Word

The Device ID Word for the PIC18F2XXX/4XXX Family devices is located at 3FFFFEh:3FFFFh. These bits may be used by the programmer to identify what device type is being programmed and read out normally, even after code or read protection.

In some cases, devices may share the same DEVID values. In such cases, the Most Significant bit of the device revision, REV4 (DEVID1<4>), will need to be examined to completely determine the device being accessed.

See Table 5-2 for a complete list of Device ID values.

FIGURE 5-1: READ DEVICE ID WORD FLOW

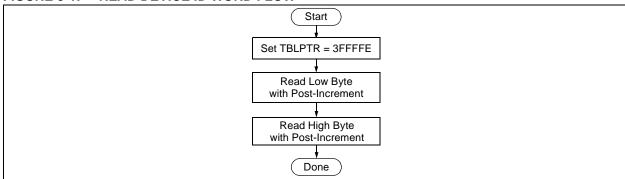


TABLE 5-1: CONFIGURATION BITS AND DEVICE IDS

File N	lame	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Default/ Unprogrammed Value											
300000h ^(1,8)	CONFIG1L	_	-	USBDIV	CPUDIV1	CPUDIV0	PLLDIV2	PLLDIV1	PLLDIV0	00 0000											
300001h	CONFIG1H	IESO	FCMEN	_	_	FOSC3	FOSC2	FOSC1	FOSC0	00 0111											
										00 0101 ^(1,8)											
300002h	CONFIG2L	_	_	VREGEN ^(1,8)	BORV1	BORV0	BOREN1	BOREN0	PWRTEN	1 1111 01 1111 ^(1,8)											
300003h	CONFIG2H			- VREGEN	WDTPS3	WDTPS2	WDTPS1	WDTPS0	WDTEN	1 1111											
-									CCP2MX ⁽⁷⁾	1011(7)											
300005h	CONFIG3H	MCLRE	_	_	_	_	LPT1OSC	PBADEN	_	101-											
		G4L DEBUG													ICPRT ⁽¹⁾	_	_				1001-1(1)
			XINST	BBSIZ1	BBSIZ0	-			STVREN	1000 -1-1											
300006h	300006h CONFIG4L			_	BBSIZ ⁽³⁾	_	LVP	LVP —		10-0 -1-1(3)											
				ICPRT ⁽⁸⁾	_	BBSIZ ⁽⁸⁾				100- 01-1(8)											
				BBSIZ1 ⁽²⁾	BBSIZ2 ⁽²⁾	ı				1000 -1-1 (2)											
300008h	CONFIG5L	_	-	CP5 ⁽¹⁰⁾	CP4 ⁽⁹⁾	CP3 ⁽⁴⁾	CP2 ⁽⁴⁾	CP1	CP0	11 1111											
300009h	CONFIG5H	CPD	СРВ	l	_	I	-	I		11											
30000Ah	CONFIG6L	_		WRT5 ⁽¹⁰⁾	WRT4 ⁽⁹⁾	WRT3 ⁽⁴⁾	WRT2 ⁽⁴⁾	WRT1	WRT0	11 1111											
30000Bh	CONFIG6H	WRTD	WRTB	WRTC ⁽⁵⁾	_	_	_	_		111											
30000Ch	CONFIG7L	_	_	EBTR5 ⁽¹⁰⁾	EBTR4 ⁽⁹⁾	EBTR3 ⁽⁴⁾	EBTR2 ⁽⁴⁾	EBTR1	EBTR0	11 1111											
30000Dh	CONFIG7H	_	EBTRB	-	_	-		_	_	-1											
3FFFFEh	DEVID1 ⁽⁶⁾	DEV2	DEV1	DEV0	REV4	REV3	REV2	REV1	REV0	See Table 5-2											
3FFFFFh	DEVID2 ⁽⁶⁾	DEV10	DEV9	DEV8	DEV7	DEV6	DEV5	DEV4	DEV3	See Table 5-2											

Legend: - = unimplemented. Shaded cells are unimplemented, read as '0'.

- Note 1: Implemented only on PIC18F2455/2550/4455/4550 and PIC18F2458/2553/4458/4553 devices.
 - 2: Implemented on PIC18F2585/2680/4585/4680, PIC18F2682/2685 and PIC18F4682/4685 devices only.
 - 3: Implemented on PIC18F2480/2580/4480/4580 devices only.
 - 4: These bits are only implemented on specific devices based on available memory. Refer to Section 2.3 "Memory Maps".
 - 5: In PIC18F2480/2580/4480/4580 devices, this bit is read-only in Normal Execution mode; it can be written only in Program mode.
 - **6:** DEVID registers are read-only and cannot be programmed by the user.
 - 7: Implemented on all devices with the exception of the PIC18FXX8X and PIC18F2450/4450 devices.
 - 8: Implemented on PIC18F2450/4450 devices only.
 - 9: Implemented on PIC18F2682/2685 and PIC18F4682/4685 devices only.
 - 10: Implemented on PIC18F2685/4685 devices only.

TABLE 5-2: DEVICE ID VALUES

Device -	Device	e ID Value
Device	DEVID2	DEVID1
PIC18F2221	21h	011x xxxx
PIC18F2321	21h	001x xxxx
PIC18F2410	11h	011x xxxx
PIC18F2420	11h	010x xxxx ⁽¹⁾
PIC18F2423	11h	010x xxxx ⁽²⁾
PIC18F2450	24h	001x xxxx
PIC18F2455	12h	011x xxxx
PIC18F2458	2Ah	011x xxxx
PIC18F2480	1Ah	111x xxxx
PIC18F2510	11h	001x xxxx
PIC18F2515	0Ch	111x xxxx
PIC18F2520	11h	000x xxxx(1)
PIC18F2523	11h	000x xxxx ⁽²⁾
PIC18F2525	0Ch	110x xxxx
PIC18F2550	12h	010x xxxx
PIC18F2553	2Ah	010x xxxx
PIC18F2580	1Ah	110x xxxx
PIC18F2585	0Eh	111x xxxx
PIC18F2610	0Ch	101x xxxx
PIC18F2620	0Ch	100x xxxx
PIC18F2680	0Eh	110x xxxx
PIC18F2682	27h	000x xxxx
PIC18F2685	27h	001x xxxx
PIC18F4221	21h	010x xxxx
PIC18F4321	21h	000x xxxx
PIC18F4410	10h	111x xxxx
PIC18F4420	10h	110x xxxx(1)
PIC18F4423	10h	110x xxxx ⁽²⁾
PIC18F4450	24h	000x xxxx
PIC18F4455	12h	001x xxxx
PIC18F4458	2Ah	001x xxxx
PIC18F4480	1Ah	101x xxxx
PIC18F4510	10h	101x xxxx
PIC18F4515	0Ch	011x xxxx
PIC18F4520	10h	100x xxxx ⁽¹⁾
PIC18F4523	10h	100x xxxx ⁽²⁾
PIC18F4525	0Ch	010x xxxx
PIC18F4550	12h	000x xxxx
PIC18F4553	2Ah	000x xxxx
PIC18F4580	1Ah	100x xxxx

Legend: The 'x's in DEVID1 contain the device revision code.

Note 1: DEVID1 bit 4 is used to determine the device type (REV4 = 0).

2: DEVID1 bit 4 is used to determine the device type (REV4 = 1).

TABLE 5-3: PIC18F2XXX/4XXX FAMILY BIT DESCRIPTIONS

Bit Name	Configuration Words	Description
IESO	CONFIG1H	Internal External Switchover bit 1 = Internal External Switchover mode is enabled 0 = Internal External Switchover mode is disabled
FCMEN	CONFIG1H	Fail-Safe Clock Monitor Enable bit 1 = Fail-Safe Clock Monitor is enabled 0 = Fail-Safe Clock Monitor is disabled
FOSC<3:0>	CONFIG1H	Oscillator Selection bits 11xx = External RC oscillator, CLKO function on RA6 101x = External RC oscillator, CLKO function on RA6 1001 = Internal RC oscillator, CLKO function on RA6, port function on RA7 1000 = Internal RC oscillator, port function on RA6, port function on RA7 0111 = External RC oscillator, port function on RA6 0110 = HS oscillator, PLL is enabled (Clock Frequency = 4 x FOSC1) 0101 = EC oscillator, port function on RA6 0100 = EC oscillator, CLKO function on RA6 0011 = External RC oscillator, CLKO function on RA6 0010 = HS oscillator 0001 = XT oscillator 0000 = LP oscillator
FOSC<3:0>	CONFIG1H	Oscillator Selection bits (PIC18F2455/2550/4455/4550, PIC18F2458/2553/4458/4553 and PIC18F2450/4450 devices only) 111x = HS oscillator, PLL is enabled, HS is used by USB 110x = HS oscillator, HS is used by USB 1011 = Internal oscillator, HS is used by USB 1010 = Internal oscillator, XT is used by USB 1001 = Internal oscillator, CLKO function on RA6, EC is used by USB 1000 = Internal oscillator, port function on RA6, EC is used by USB 0111 = EC oscillator, PLL is enabled, CLKO function on RA6, EC is used by USB 0110 = EC oscillator, PLL is enabled, port function on RA6, EC is used by USB 0101 = EC oscillator, CLKO function on RA6, EC is used by USB 0100 = EC oscillator, port function on RA6, EC is used by USB 010x = XT oscillator, PLL is enabled, XT is used by USB 000x = XT oscillator, XT is used by USB
USBDIV	CONFIG1L	USB Clock Selection bit (PIC18F2455/2550/4455/4550, PIC18F2458/2553/4458/4553 and PIC18F2450/4450 devices only) Selects the clock source for full-speed USB operation: 1 = USB clock source comes from the 96 MHz PLL divided by 2 0 = USB clock source comes directly from the OSC1/OSC2 oscillator block; no divide
CPUDIV<1:0>	CONFIG1L	CPU System Clock Selection bits (PIC18F2455/2550/4455/4550, PIC18F2458/2553/4458/4553 and PIC18F2450/4450 devices only) 11 = CPU system clock divided by 4 10 = CPU system clock divided by 3 01 = CPU system clock divided by 2 00 = No CPU system clock divide

Note 1: The BBSIZ bits, BBSIZ<1:0> and BBSIZ<2:1> bits, cannot be changed once any of the following code-protect bits are enabled: CPB or CP0, WRTB or WRT0, EBTRB or EBTR0.

2: Not available in PIC18FXX8X and PIC18F2450/4450 devices.

TABLE 5-3: PIC18F2XXX/4XXX FAMILY BIT DESCRIPTIONS (CONTINUED)

Bit Name	Configuration Words	Description						
BBSIZ<1:0> ⁽¹⁾	CONFIG4L	Boot Block Size Select bits (PIC18F2321/4321 devices only) 11 = 1K word (2 Kbytes) Boot Block 10 = 1K word (2 Kbytes) Boot Block 01 = 512 words (1 Kbyte) Boot Block 00 = 256 words (512 bytes) Boot Block						
		Boot Block Size Select bits (PIC18F2221/4221 devices only) 11 = 512 words (1 Kbyte) Boot Block 10 = 512 words (1 Kbyte) Boot Block 01 = 512 words (1 Kbyte) Boot Block 00 = 256 words (512 bytes) Boot Block						
BBSIZ ⁽¹⁾	CONFIG4L	Boot Block Size Select bits (PIC18F2480/2580/4480/4580 and PIC18F2450/4450 devices only) 1 = 2K words (4 Kbytes) Boot Block 0 = 1K word (2 Kbytes) Boot Block						
LVP	CONFIG4L	Low-Voltage Programming Enable bit 1 = Low-Voltage Programming is enabled, RB5 is the PGM pin 0 = Low-Voltage Programming is disabled, RB5 is an I/O pin						
STVREN	CONFIG4L	Stack Overflow/Underflow Reset Enable bit 1 = Reset on stack overflow/underflow is enabled 0 = Reset on stack overflow/underflow is disabled						
CP5	CONFIG5L	Code Protection bit (Block 5 code memory area) (PIC18F2685 and PIC18F4685 devices only) 1 = Block 5 is not code-protected 0 = Block 5 is code-protected						
CP4	CONFIG5L	Code Protection bit (Block 4 code memory area) (PIC18F2682/2685 and PIC18F4682/4685 devices only) 1 = Block 4 is not code-protected 0 = Block 4 is code-protected						
CP3	CONFIG5L	Code Protection bit (Block 3 code memory area) 1 = Block 3 is not code-protected 0 = Block 3 is code-protected						
CP2	CONFIG5L	Code Protection bit (Block 2 code memory area) 1 = Block 2 is not code-protected 0 = Block 2 is code-protected						
CP1	CONFIG5L	Code Protection bit (Block 1 code memory area) 1 = Block 1 is not code-protected 0 = Block 1 is code-protected						
CP0	CONFIG5L	Code Protection bit (Block 0 code memory area) 1 = Block 0 is not code-protected 0 = Block 0 is code-protected						
CPD	CONFIG5H	Code Protection bit (Data EEPROM) 1 = Data EEPROM is not code-protected 0 = Data EEPROM is code-protected						
СРВ	CONFIG5H	Code Protection bit (Boot Block memory area) 1 = Boot Block is not code-protected 0 = Boot Block is code-protected						

Note 1: The BBSIZ bits, BBSIZ<1:0> and BBSIZ<2:1> bits, cannot be changed once any of the following code-protect bits are enabled: CPB or CP0, WRTB or WRT0, EBTRB or EBTR0.

^{2:} Not available in PIC18FXX8X and PIC18F2450/4450 devices.

TABLE 5-3: PIC18F2XXX/4XXX FAMILY BIT DESCRIPTIONS (CONTINUED)

Bit Name	Configuration Words	Description				
EBTR0	CONFIG7L	Table Read Protection bit (Block 0 code memory area)				
		 1 = Block 0 is not protected from Table Reads executed in other blocks 0 = Block 0 is protected from Table Reads executed in other blocks 				
EBTRB	CONFIG7H	Table Read Protection bit (Boot Block memory area)				
		 1 = Boot Block is not protected from Table Reads executed in other blocks 0 = Boot Block is protected from Table Reads executed in other blocks 				
DEV<10:3>	DEVID2	Device ID bits				
		These bits are used with the DEV<2:0> bits in the DEVID1 register to identify part number.				
DEV<2:0>	DEVID1	Device ID bits				
		These bits are used with the DEV<10:3> bits in the DEVID2 register to identify part number.				
REV<4:0>	DEVID1	Revision ID bits				
		These bits are used to indicate the revision of the device. The REV4 bit is sometimes used to fully specify the device type.				

Note 1: The BBSIZ bits, BBSIZ<1:0> and BBSIZ<2:1> bits, cannot be changed once any of the following code-protect bits are enabled: CPB or CP0, WRTB or WRT0, EBTRB or EBTR0.

^{2:} Not available in PIC18FXX8X and PIC18F2450/4450 devices.

TABLE 5-4: DEVICE BLOCK LOCATIONS AND SIZES

Device	Memory Size (Bytes)				End	ing Addr	ess			Size (Bytes)			
		Pins	Boot Block	Block 0	Block 1	Block 2	Block 3	Block 4	Block 5	Boot Block	Block 0	Remaining Blocks	Device Total
PIC18F2221 4K	414	28	0001FF	001FF	000555					512	1536	2048	4096
	28	0003FF	0007FF	000FFF	_	_	_	_	1024	1024	20 4 0	4096	
PIC18F2321 8K			0001FF							512	3584		
	28	0003FF	000FFF	001FFF	_	_	_	_	1024	3072	4096	8192	
			0007FF						[2048	2048		
PIC18F2410	16K	28	0007FF	001FFF	003FFF	_	-	_	_	2048	6144	8192	16384
PIC18F2420	16K	28	0007FF	001FFF	003FFF	_			_	2048	6144	8192	16384
PIC18F2423	16K	28	0007FF	001FFF	003FFF	_	-	_	_	2048	6144	8192	16384
DIO4650 :	16K	28	0007FF	004555	000555					2048	6144	8192	40004
PIC18F2450	ION	20	000FFF	001FFF	003FFF	_		_		4096	4096		16384
PIC18F2455	24K	28	0007FF	001FFF	003FFF	005FFF	_	_	_	2048	6144	16384	24576
PIC18F2458	24K	28	0007FF	001FFF	003FFF	005FFF	_	_	_	2048	6144	16384	24576
DIO4050400	4016	-00	0007FF	004555						2048	6144	0400	16384
PIC18F2480	16K	28	000FFF	001FFF	003FFF		_		_	4096	4096	8192	
PIC18F2510	32K	28	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	6144	24576	32768
PIC18F2515	48K	28	0007FF	003FFF	007FFF	00BFFF	_	_	_	2048	14336	32768	49152
PIC18F2520	32K	28	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	14336	16384	32768
PIC18F2523	32K	28	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	14336	16384	32768
PIC18F2525	48K	28	0007FF	003FFF	007FFF	00BFFF	_	_	_	2048	14336	32768	49152
PIC18F2550	32K	28	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	6144	24576	32768
PIC18F2553	32K	28	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	6144	24576	32768
PIC18F2580	32K	28	0007FF		003FFF	005FFF	007FFF	_	_	2048	6144	24576	32768
			000FFF	001FFF						4096	4096		
		8K 28	0007FF	003FFF	007FFF	00BFFF	_	_	_	2048	14336	32768	49152
PIC18F2585	48K		000FFF							4096	12288		
1 10 101 2000			001FFF							8192	8192		
PIC18F2610	64K	28	0007FF	003FFF	007FFF	00BFFF	00FFFF	_	_	2048	14336	49152	65536
PIC18F2620	64K	28	0007FF	003FFF	007FFF	00BFFF	00FFFF	_	_	2048	14336	49152	65536
PIC18F2680	64K	28	0007FF	003FFF	007FFF		00FFFF	_	_	2048	14336	49152	65536
			000FFF							4096	12288		
			001FFF							8192	8192		
PIC18F2682	80K	28	0007FF	003FFF	007FFF	00BFFF	00FFFF	013FFF	_	2048	14336	65536	81920
			000FFF							4096	12288		
			001FFF							8192	8192		
PIC18F2685	96K	28	0007FF	003FFF	007FFF	00BFFF	00FFFF	013FFF	017FFF	2048	14336	81920	98304
			000FFF							4096	12288		
	0011		001FFF	000111						8192	8192		
	4K		0001FF	0007FF	000FFF	_	_	_		512	1536	2048	4096
PIC18F4221		40	0003FF						_	1024	1024		
	8K		0000FF		001FFF				_	512	3584	4096	8192
PIC18F4321		40	0003FF	000FFF						1024	3072		
F 10 101 4321			0000FF	000111	001111					2048	2048	4000	
PIC18F4410	16K	40	0007FF	001FFF	003FFF					2048	6144	8192	16384
PIC18F4410	16K	40	0007FF	001FFF	003FFF					2048	6144	8192	16384
PIC18F4423		40	0007FF	001FFF	003FFF					2048	6144		
1 10 101 4423	ION	16K 40 16K 40	0007FF	JUIL ET	0001 FF		_	_	_	2048	6144	8192 - 8192	16384
PIC18F4450	16K		0007FF	001FFF	003FFF				_	4096	4096		
l egend:	-									4090	4090		

Legend:

— = unimplemented.

6.0 AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY TEST MODE (CONTINUED)

Standard Operating Conditions Operating Temperature: 25°C is recommended **Param** Sym Characteristic Min Max Units Conditions No. P11A Data Write Polling Time **T**DRWT 4 ms Input Data Hold Time from MCLR/VPP/RE3 ↑ P12 THLD2 2 μS VDD ↑ Setup Time to MCLR/VPP/RE3 ↑ P13 TSET2 100 (Note 2) ns P14 TVALID Data Out Valid from PGC ↑ 10 ns P15 TSET3 PGM ↑ Setup Time to MCLR/VPP/RE3 ↑ 2 (Note 2) цS Delay Between Last PGC ↓ and MCLR/VPP/RE3 ↓ P16 TDLY8 0 s THLD3 MCLR/VPP/RE3 ↓ to VDD ↓ 100 ns P18 MCLR/VPP/RE3 ↓ to PGM ↓ 0 THLD4

1 TCY + TPWRT (if enabled) + 1024 ToSC (for LP, HS, HS/PLL and XT modes only) +

where TCY is the instruction cycle time, TPWRT is the Power-up Timer period and ToSC is the oscillator period. For specific values, refer to the Electrical Characteristics section of the device data sheet for the particular device.

- 2: When ICPRT = 1, this specification also applies to ICVPP.
- 3: At 0°C-50°C.

Note 1: Do not allow excess time when transitioning MCLR between VIL and VIHH. This can cause spurious program executions to occur. The maximum transition time is:

² ms (for HS/PLL mode only) + 1.5 μ s (for EC mode only)